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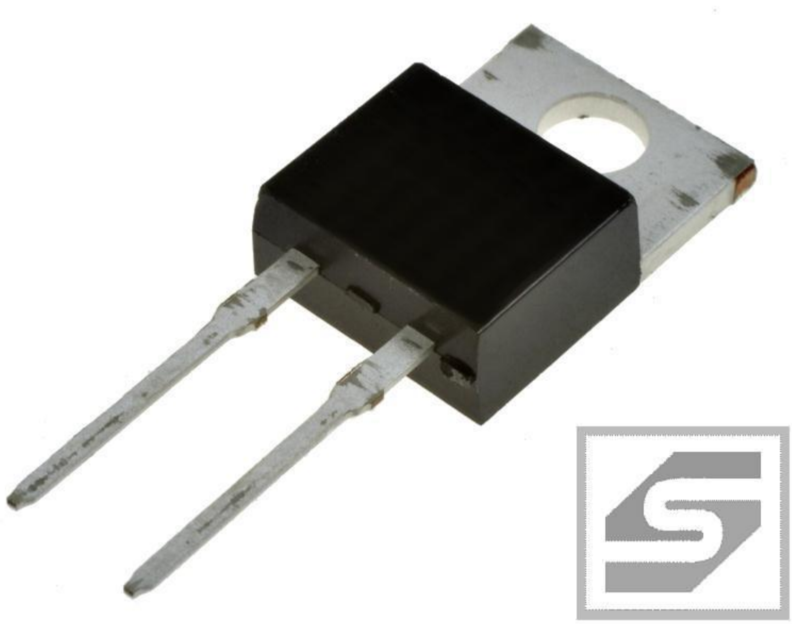
Dioda RHRP3060 FSC 30A 600V 18ns TO220AC



Dane techniczne:
Nazwa: RHRP3060
Typ: dioda szybka
Napięcie wsteczne maksymalne: 600V
Napięcie przewodzenia maksymalne: 2,1V
Prąd przewodzenia: 30A
Prąd przewodzenia maksymalny: 70A
Prąd w impulsie maksymalny: 325A
Moc rozpraszana: 125W
Czas gotowości: 18ns
Obudowa: TO220AC
Montaż: przewlekany(THT)

30A, 400V - 600V Hyperfast Diodes

The RHRP3040 and RHRP3060 are hyperfast diodes with soft recovery characteristics (t_{rr} < 40ns). They have half the recovery time of ultrafast diodes and are of silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Formerly developmental type TA49063.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RHRP3040	TO-220AC	RHRP3040
RHRP3060	TO-220AC	RHRP3060

NOTE: When ordering, use the entire part number.

Symbol

Features

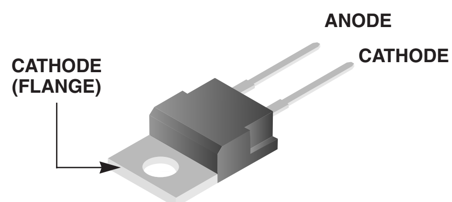
- Hyperfast with Soft Recovery . . . . <40ns
- Operating Temperature . . . . 175^oC
- Reverse Voltage Up To 600V
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

Packaging

JEDEC TO-220AC



Absolute Maximum Ratings $T_C = 25^oC$, Unless Otherwise Specified

	RHRP3040	RHRP3060	UNITS
Peak Repetitive Reverse Voltage . . . . V_{RRM}	400	600	V
Working Peak Reverse Voltage . . . . V_{RWM}	400	600	V
DC Blocking Voltage . . . . V_R	400	600	V
Average Rectified Forward Current . . . . $I_{F(AV)}$ ($T_C = 120^oC$)	30	30	A
Repetitive Peak Surge Current . . . . I_{FRM} (Square Wave, 20kHz)	70	70	A
Nonrepetitive Peak Surge Current . . . . I_{FSM} (Halfwave, 1 Phase, 60Hz)	325	325	A
Maximum Power Dissipation . . . . P_D	125	125	W
Avalanche Energy (See Figures 10 and 11) . . . . E_{AVL}	20	20	mJ
Operating and Storage Temperature . . . . T_{STG}, T_J	-65 to 175	-65 to 175	^oC

Electrical Specifications $T_C = 25^oC$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	RHRP3040 MIN	RHRP3040 TYP	RHRP3040 MAX	RHRP3060 MIN	RHRP3060 TYP	RHRP3060 MAX	UNITS
V_F	I_F = 30A	-	-	2.1	-	-	2.1	V
	I_F = 30A, T_C = 150^{o}C	-	-	1.7	-	-	1.7	V
I_R	V_R = 400V	-	-	250	-	-	-	μA
	V_R = 600V	-	-	-	-	-	250	μA
	V_R = 400V, T_C = 150^{o}C	-	-	1.0	-	-	-	mA
	V_R = 600V, T_C = 150^{o}C	-	-	-	-	-	1.0	mA
t_{rr}	I_F = 1A, dI_F/dt = 200A/μs	-	-	40	-	-	40	ns
	I_F = 30A, dI_F/dt = 200A/μs	-	-	45	-	-	45	ns
t_a	I_F = 30A, dI_F/dt = 200A/μs	-	22	-	-	22	-	ns
t_b	I_F = 30A, dI_F/dt = 200A/μs	-	18	-	-	18	-	ns
Q_{RR}	I_F = 30A, dI_F/dt = 200A/μs	-	100	-	-	100	-	nC
C_J	V_R = 10V, I_F = 0A	-	85	-	-	85	-	pF
$R_{\theta JC}$		-	-	1.2	-	-	1.2	^{o}C/W

DEFINITIONS

V_F = Instantaneous forward voltage (pw = 300μs, D = 2%).

I_R = Instantaneous reverse current .

t_{rr} = Reverse recovery time (See Figure 9), summation of $t_a + t_b$.

t_a = Time to reach peak reverse current (See Figure 9).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse recovery charge.

C_J = Junction Capacitance.

$R_{\theta JC}$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

Typical Performance Curves

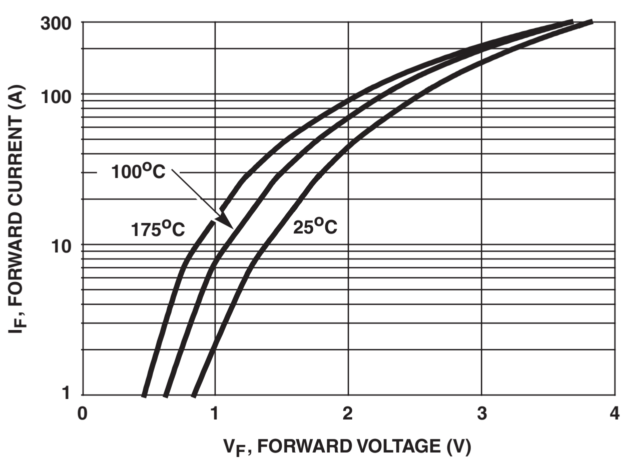


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

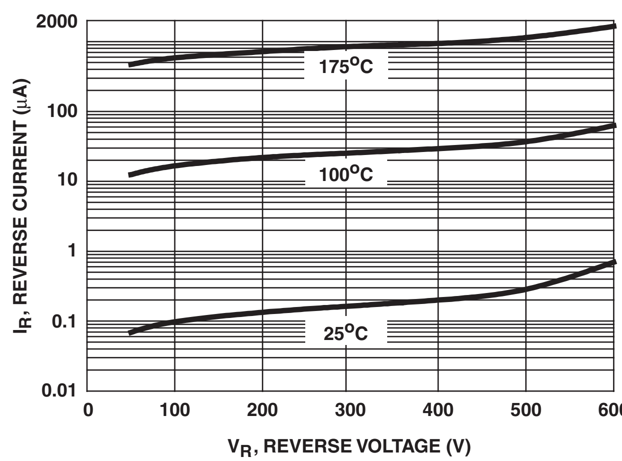


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

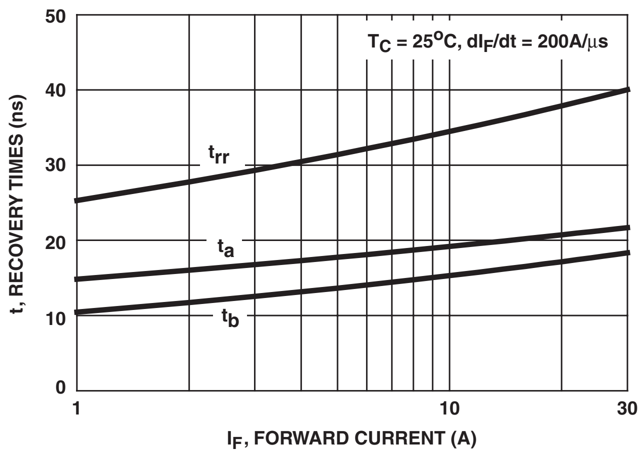


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

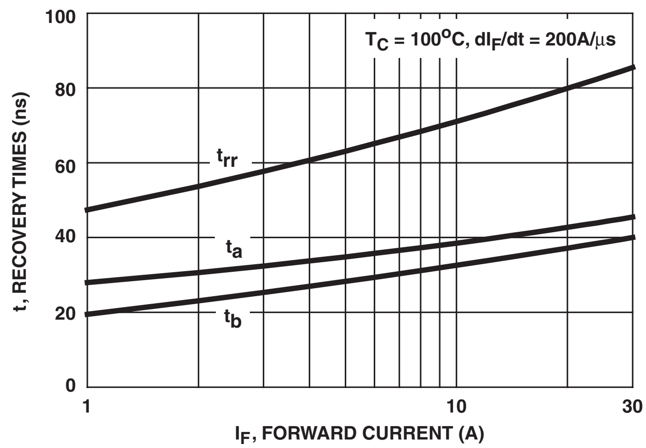


FIGURE 4. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

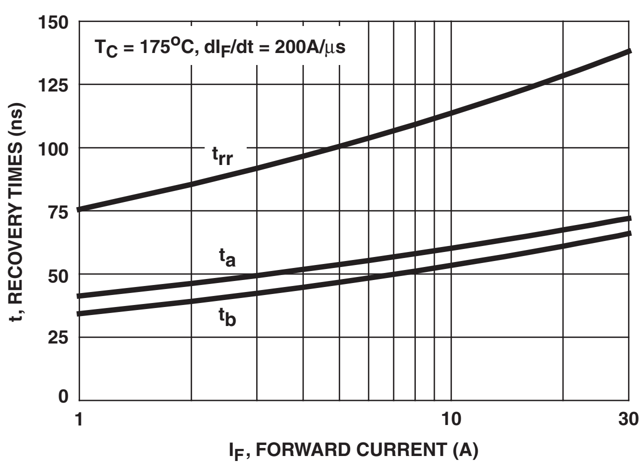


FIGURE 5. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

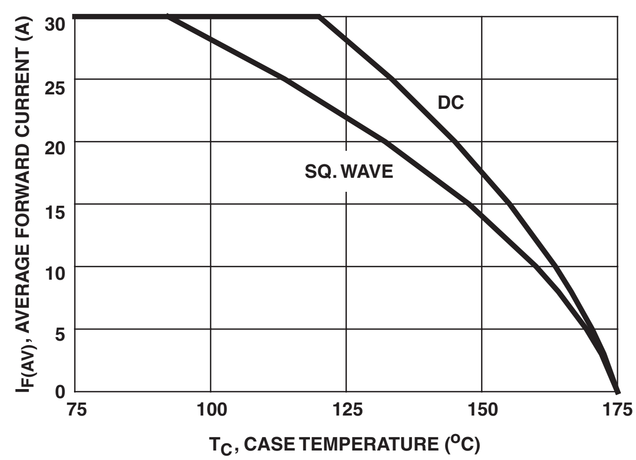


FIGURE 6. CURRENT DERATING CURVE

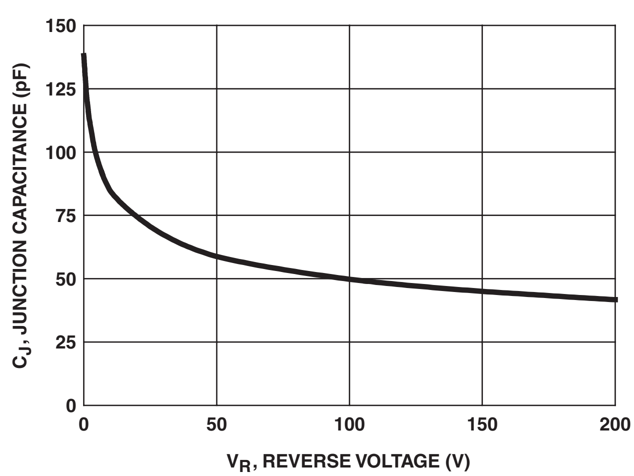


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

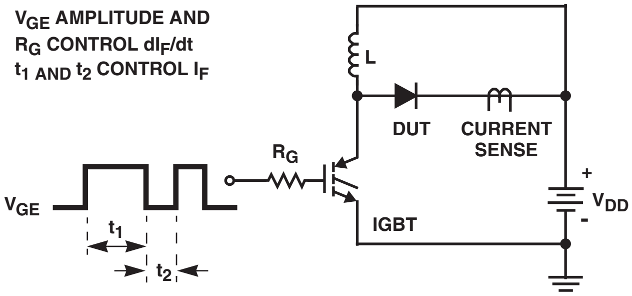


FIGURE 8. t_{rr} TEST CIRCUIT

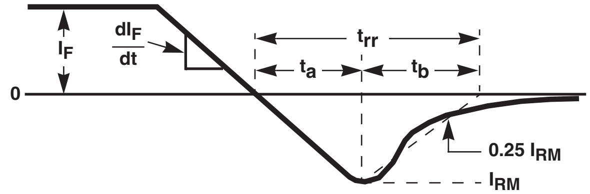


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

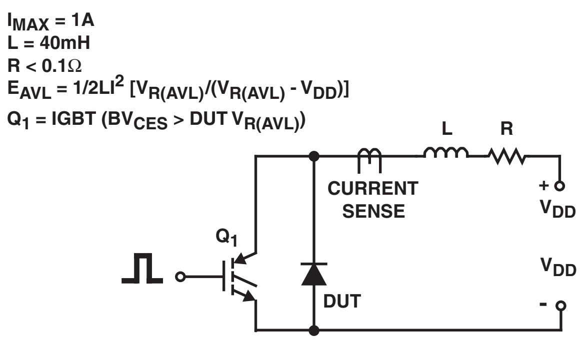


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

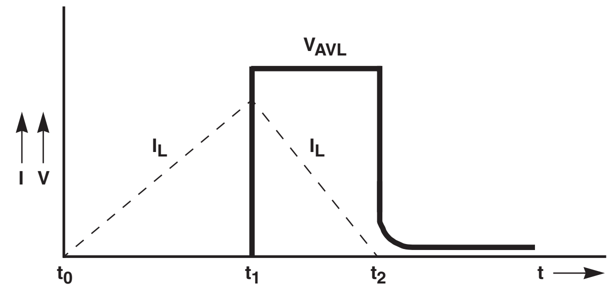


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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DOME™	HiSeC™	PowerTrench®	SuperSOT™-8	
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